

SEMICONDUCTOR®

FDZ663P

December 2011

P-Channel 1.5 V Specified PowerTrench $^{\mbox{\scriptsize R}}$ Thin WL-CSP MOSFET -20 V, -2.7 A, 134 m Ω

Features

- Max $r_{DS(on)}$ = 134 m Ω at V_{GS} = -4.5 V, I_D = -2 A
- Max $r_{DS(on)}$ = 171 m Ω at V_{GS} = -2.5 V, I_D = -1.5 A
- Max $r_{DS(on)}$ = 216 m Ω at V_{GS} = -1.8 V, I_D = -1 A
- Max r_{DS(on)} = 288 mΩ at V_{GS} = -1.5 V, I_D = -1 A
- Occupies only 0.64 mm² of PCB area. Less than 16% of the area of 2 x 2 BGA
- Ultra-thin package: less than 0.4 mm height when mounted to PCB
- RoHS Compliant

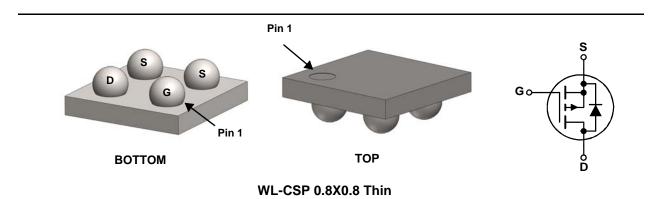


General Description

Designed on Fairchild's advanced 1.5 V PowerTrench[®] process with state of the art "fine pitch" Thin WLCSP packaging process, the FDZ663P minimizes both PCB space and $r_{DS(on)}$. This advanced WLCSP MOSFET embodies a breakthrough in packaging technology which enables the device to combine excellent thermal transfer characteristics, ultra-low profile (0.4 mm) and small (0.8x0.8 mm²) packaging, low gate charge, and low $r_{DS(on)}$.

Applications

- Battery management
- Load switch
- Battery protection



MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			-20	V	
V _{GS}	Gate to Source Voltage			±8	V	
	-Continuous	T _A = 25 °C	(Note 1a)	-2.7	٨	
I _D	-Pulsed			-10	A	
P _D	Power Dissipation	T _A = 25 °C	(Note 1a)	1.3	14/	
	Power Dissipation	T _A = 25 °C	(Note 1b)	0.4	W	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

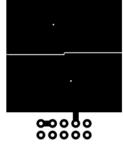
Thermal Characteristics

R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1a)	93	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	311	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
EJ	FDZ663P	WL-CSP 0.8X0.8 Thin	7 "	8 mm	5000 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	octeristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = -250 \ \mu A, V_{GS} = 0 \ V$	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, referenced to 25 °C		-14		mV/°C
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$			±60	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \ \mu A$	-0.3	-0.7	-1.2	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, referenced to 25 °C		2.4		mV/°C
	Static Drain to Source On Resistance	$V_{GS} = -4.5 \text{ V}, I_D = -2 \text{ A}$		103	134	
r _{DS(on)}		V _{GS} = -2.5 V, I _D = -1.5 A		122	171	1
		V _{GS} = -1.8 V, I _D = -1 A		149	216	mΩ
		V _{GS} = -1.5 V, I _D = -1 A		186	288	
		V_{GS} = -4.5 V, I_D = -2 A, T_J =125°C		137	198	
9 _{FS}	Forward Transconductance	$V_{DD} = -5 V, I_D = -2 A$		8		S
C _{iss} C _{oss}	Characteristics Input Capacitance Output Capacitance	− V _{DS} = -10 V, V _{GS} = 0 V, − f = 1 MHz		394 62	525 85	pF pF
C _{rss}	Reverse Transfer Capacitance			53	80	pF
Switching	g Characteristics					
t _{d(on)}	Turn-On Delay Time			4.8	10	ns
t _r	Rise Time	V _{DD} = -10 V, I _D = -2.5 A,		6.2	12	ns
t _{d(off)}	Turn-Off Delay Time	V_{GS} = -4.5 V, R_{GEN} = 6 Ω		67	107	ns
t _f	Fall Time			32	52	ns
Qg	Total Gate Charge	V 45V/V 40V/		5.9	8.2	nC
Q _{gs}	Gate to Source Charge	──V _{GS} = -4.5 V, V _{DD} = -10 V, I _D = -2.5 A		0.6		nC
Q _{gd}	Gate to Drain "Miller" Charge	10 - 2.0 /		1.6		nC
Drain-Sou	urce Diode Characteristics					
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = -1.4 A$ (Note 2)		-0.8	-1.2	V
t _{rr}	Reverse Recovery Time			30	48	ns
Q _{rr}	Reverse Recovery Charge	I _F = -2.5 A, di/dt = 100 A/μs		10	18	nC



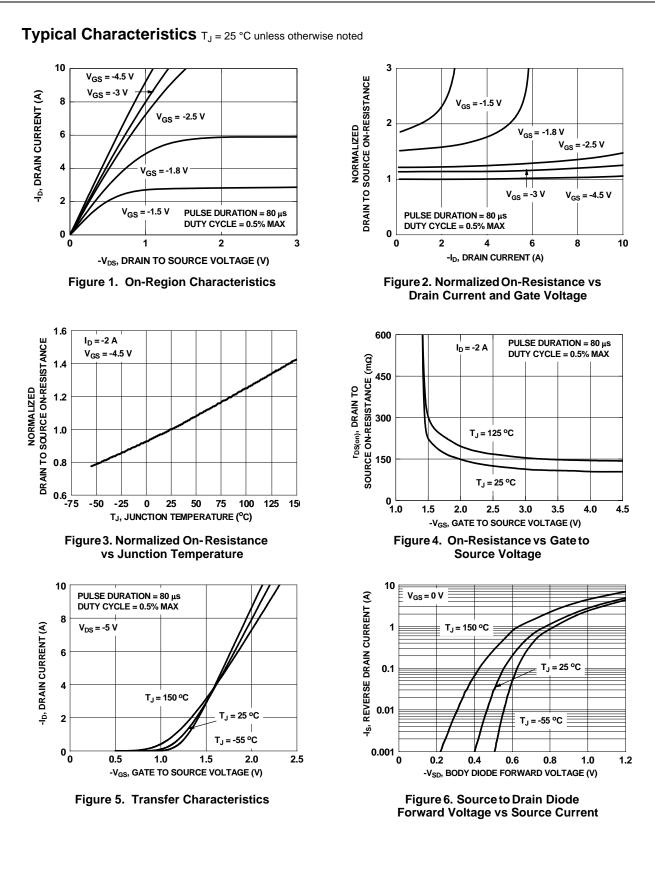
2. Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0%.

ad of 2 oz copper.



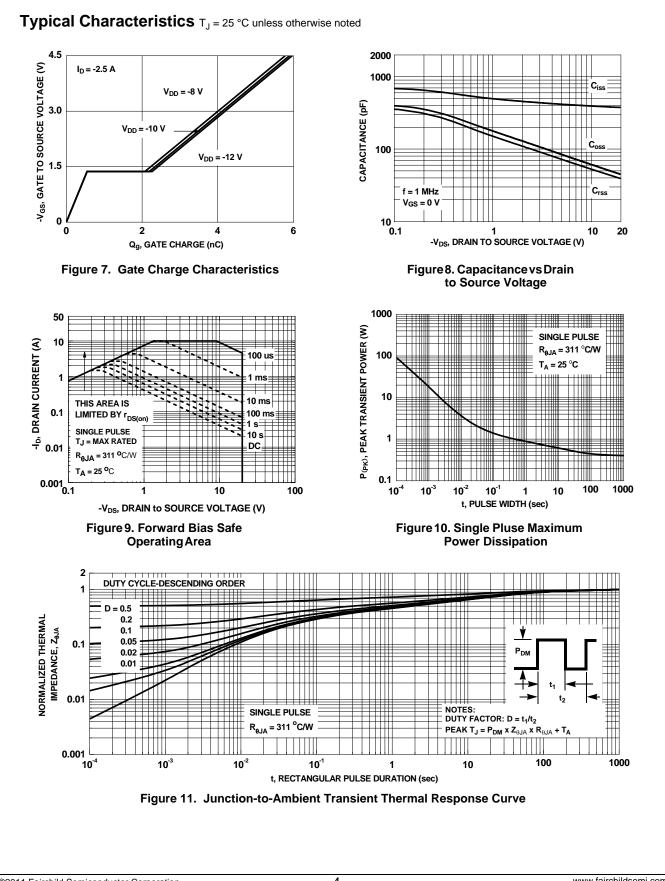
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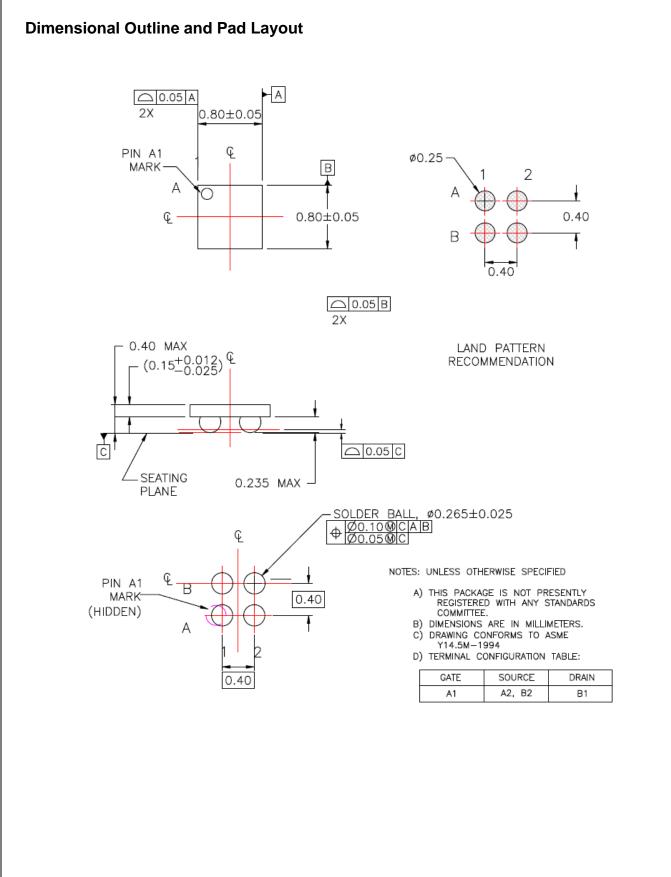


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